NSN 5961-01-260-0556

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-260-0556 **Inclosure Material:** Glass and metal **Overall Length:** 0.755 inches **Overall Height:** 0.570 inches **Overall Width:** 0.755 inches **Mounting Facility Quantity: Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, instantaneous all semiconductor device diode **Current Rating Per Characteristic:** 6.00 amperes source cutoff current preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 4 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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